گروه فنی مهندسی جوش و برش مقدم

اعتماد از شما کیفیت و تخصص از ما

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مشهد خیام شمالی 63 خیابان پردیس 3

برای کسب اطلاعات بیشتر بر روی لینک ها کلیک کنید

- 7 سال سابقه آموزش تعمیرات تخصصی دستگاه های جوش اینورتری تک فاز و 3 فاز
- 7 سال سابقه فروش قطعات الکترونیکی دستگاه جوش تک فاز و 3 فاز
- آموزش تخصصی تحلیل دستگاه های جوش اینورتری مختص ابراز فروشان
- آموزش تخصصی ابراز آلات شارژی

PC817XxNSZ1B Series

DIP 4pin Photocoupler

■ Description

PC817XxNSZ1B Series contains an IRED optically coupled to a phototransistor.
It is packaged in a 4-pin DIP.
Input-output isolation voltage(rms) is 5kV.
Collector-emitter voltage is 80V.
CTR is 50% to 400% (at I_F=5mA,V_{CE}=5V,Ta=25℃)

■ Features

1. 4-pin DIP package
2. Double transfer mold package
   (Ideal for Flow Soldering)
3. High isolation voltage between input and output
   (Viso(rms) : 5kV)
4. High collector-emitter voltage(V_{CEO} : 80V)
5. Current transfer ratio
   (CTR : MIN. 50% at I_F=5 mA, V_{CE}=5V ,Ta=25℃)
6. RoHS directive compliant

■ Agencyapprovals/Compliance

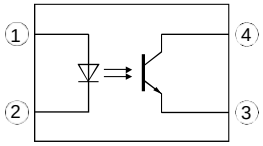
1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC817**)
2. Approved by CSA
   file No. CA95323 (as model No**. PC817**)
3. Package resin : UL flammability grade (94V-0)

■ Applications

1. Programmable controllers
2. Facsimiles
3. Telephones

Sheet No.: OP18002EN
DATE Jan.15.2018

■ Internal Connection Diagram

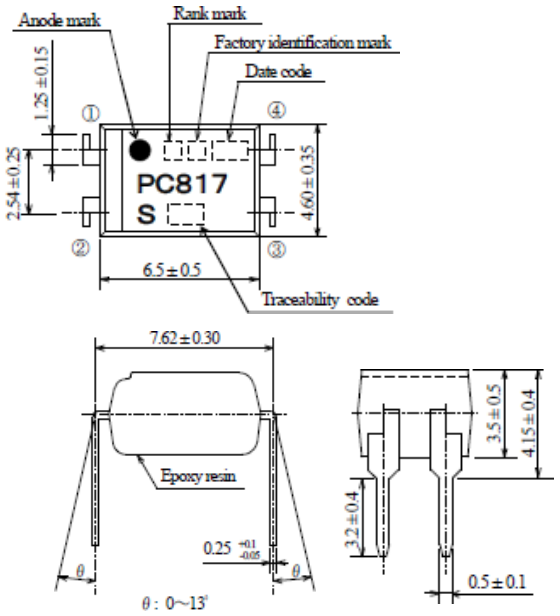


① Anode
② Cathode
③ Emitter
④ Collector

■ Outline

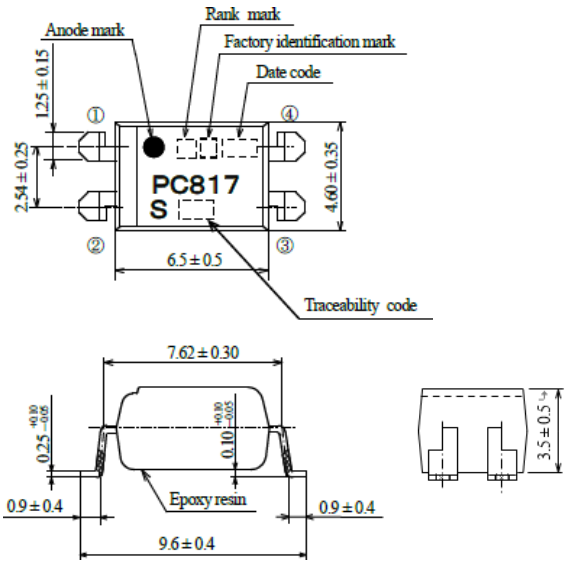
(Unit : mm)

1 . Through-Hole
[ex. PC817XNNSZ1B]



Product mass : approx. 0.23g

2 . SMT Gullwing Lead-Form
[ex . PC817XNNIP1B]



Product mass : approx. 0.22g

Date code indication (Ex.)

3-digit number shall be marked the age indication of 1-digit number, and week code of 2-digit number.
Week code "01" indicate the week including the first Thursday of January. And later, Monday is the starting point.

Year	Week

Date code	MON	TUE	WED	THU	FRI	SAT	SUN
652	12/26	12/27	12/28	12/29	12/30	12/31	1/1
701	1/2	1/3	1/4	1/5	1/6	1/7	1/8
702	1/9	1/10	1/11	1/12	1/13	1/14	1/15
703	1/16	1/17	1/18	1/19	1/20	1/21	1/22
⋮	⋮	⋮	⋮	⋮	⋮	⋮	⋮
752	12/11	12/12	12/13	12/14	12/15	12/16	12/17
751	12/18	12/19	12/20	12/21	12/22	12/23	12/24
752	12/25	12/26	12/27	12/28	12/29	12/30	12/31
801	1/1	1/2	1/3	1/4	1/5	1/6	1/7

Factory identification mark and Plating material

Factory identification Mark	Country of origin	Plating material
K	Japan	SnBi (Bi : 1 ~ 4%)

Rank mark

Refer to the Model Line-up table.

■ Absolute Maximum Ratings

(T_a=25℃)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	*1 Peak forward current	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V_{CEO}	80	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_C	50	mA
	Collector power dissipation	P_C	150	mW
Total power dissipation		P_{tot}	200	mW
*2 Isolation voltage		V_{iso}(rms)	5	kV
Operating temperature		T_{opr}	–30 to +100	℃
Storage temperature		T_{stg}	–55 to +125	℃
*2 Soldering temperature		T_{sol}	270	℃

*1 Pulse width≦100μs, Duty ratio : 0.001
*2 40 to 60%RH, AC for 1 minute
*3 For 10s

■ Electro-optical Characteristics

(T_a=25℃)

Parameter			Symbol	Condition	MIN.	TYP.	MAX.	Unit
Input	Forward voltage		V_F	I_F=20mA	–	1.2	1.4	V
	Peak forward voltage		V_{FM}	I_{FM}=0.5A	–	–	3.0	V
	Reverse current		I_R	V_R=4V	–	–	10	μA
	Terminal capacitance		C_t	V=0, f=1kHz	–	30	250	pF
Output	Dark current		I_{CEO}	V_{CE}=50V, I_F=0	–	–	100	nA
	Collector-emitter breakdown voltage		BV_{CEO}	I_C=0.1mA, I_F=0	80	–	–	V
	Emitter-collector breakdown voltage		BV_{ECO}	I_E=10μA, I_F=0	6	–	–	V
Transfer charac–teristics	Collector current		I_C	I_F=5mA, V_{CE}=5V	2.5	–	30	mA
	Collector-emitter saturation voltage		$V_{CE(sat)}$	I_F=20mA, I_C=1mA	–	0.1	0.2	V
	Isolation resistance		R_{ISO}	DC500V, 40 to 60%RH	5×10^{10}	1×10^{11}	–	Ω
	Floating capacitance		C_f	V=0, f=1MHz	–	0.6	1.0	pF
	Cut-off frequency		f_C	V_{CE}=5V, I_C=2mA, R_L=100Ω, –3dB	–	80	–	kHz
	Response time	Risetime	t_r	V_{CE}=2V, I_C=2mA, R_L=100Ω	–	4	18	μs
		Fall time	t_f		–	3	18	μs

■ Model Line-up

Lead Form	Through-Hole	Rank mark	I_C[mA] (I_F=5mA, V_{CE}=5V, T_a=25˚C)
	Sleeve		
Package	100pcs/sleeve		
Model No.	**PC817XNNSZ1B**	with or "_"	2.5 ~ 30
	PC817X1NSZ1B	A	4.0 ~ 8.0
	PC817X2NSZ1B	B	6.5 ~ 13
	PC817X3NSZ1B	C	10 ~ 20
	PC817X4NSZ1B	D	15 ~ 30
	PC817X5NSZ1B	A or B	4.0 ~ 13
	PC817X6NSZ1B	B or C	6.5 ~ 20
	PC817X7NSZ1B	C or D	10 ~ 30
	PC817X8NSZ1B	A, B or C	4.0 ~ 20
	PC817X9NSZ1B	B, C or D	6.5 ~ 30
	PC817X0NSZ1B	A, B, C or D	4.0 ~ 30

Lead Form	SMT Gullwing	Rank mark	I_C[mA] (I_F=5mA, V_{CE}=5V, T_a=25˚C)
	Taping		
Package	2,000pcs/reel		
Model No.	**PC817XNNIP1B**	with or "_"	2.5 ~ 30
	PC817X1NIP1B	A	4.0 ~ 8.0
	PC817X2NIP1B	B	6.5 ~ 13
	PC817X3NIP1B	C	10 ~ 20
	PC817X4NIP1B	D	15 ~ 30
	PC817X5NIP1B	A or B	4.0 ~ 13
	PC817X6NIP1B	B or C	6.5 ~ 20
	PC817X7NIP1B	C or D	10 ~ 30
	PC817X8NIP1B	A, B or C	4.0 ~ 20
	PC817X9NIP1B	B, C or D	6.5 ~ 30
	PC817X0NIP1B	A, B, C or D	4.0 ~ 30

Please contact a local SHARP sales representative to inquire about productionstatus.

Fig.1 Forward Current vs. Ambient Temperature

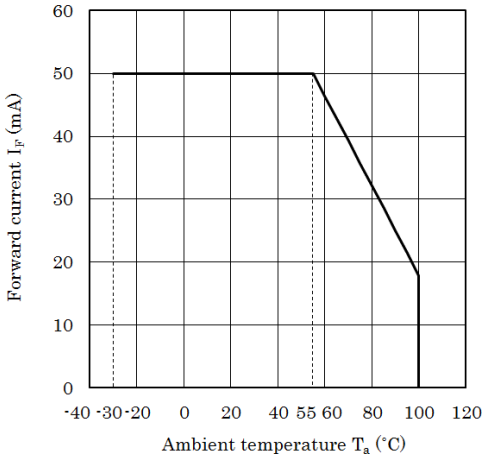


Fig.2 Diode Power Dissipation vs. Ambient Temperature

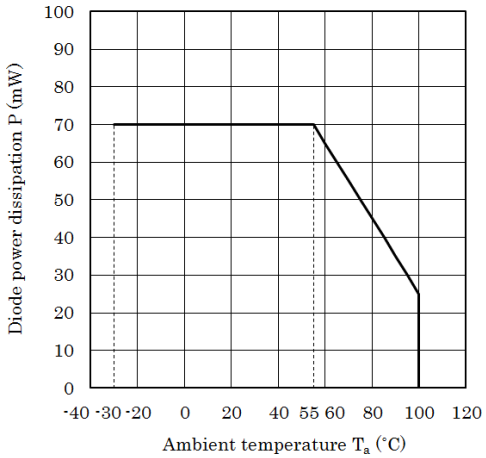


Fig.3 Collector Power Dissipation vs. Ambient Temperature

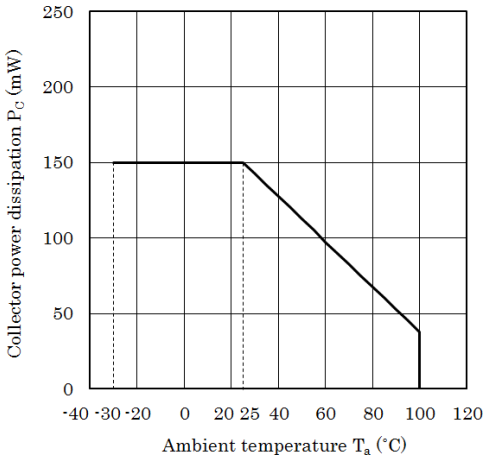


Fig.4 Total Power Dissipation vs. Ambient Temperature

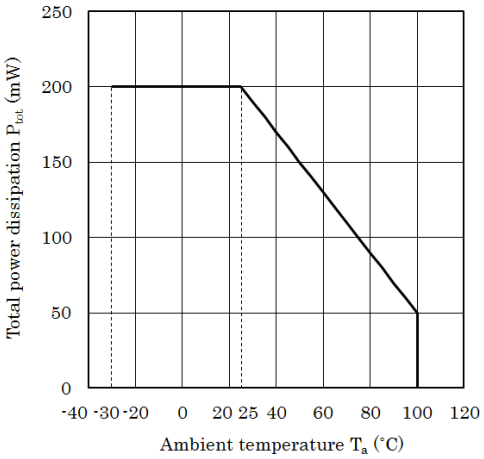
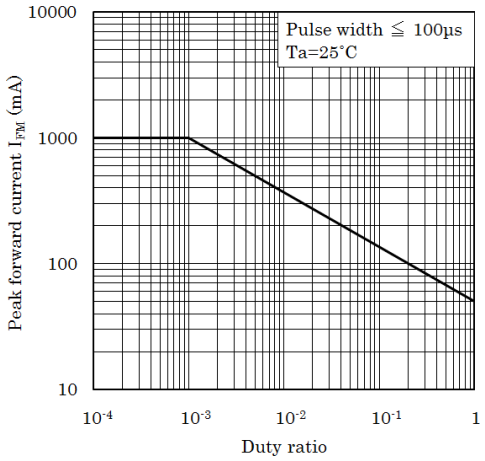


Fig.5 Peak Forward Current vs. Duty Ratio

Fig.6 Forward Current vs. Forward Voltage


Pulse width ≦ 100μs
Ta=25°C
Peak forward current I_{FM} (mA)
10000
1000
100
10
10^{-4}
10^{-3}
10^{-2}
10^{-1}
1
Duty ratio

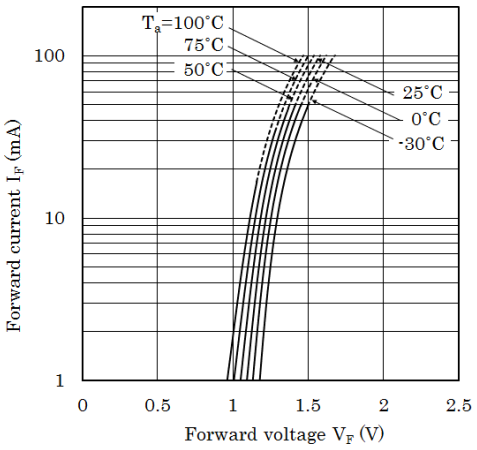

T_a=100°C
75°C
50°C
25°C
0°C
-30°C
Forward current I_F (mA)
100
10
1
0
0.5
1
1.5
2
2.5
Forward voltage V_F (V)

Fig.7 Current Transfer Ratio vs. Forward Current

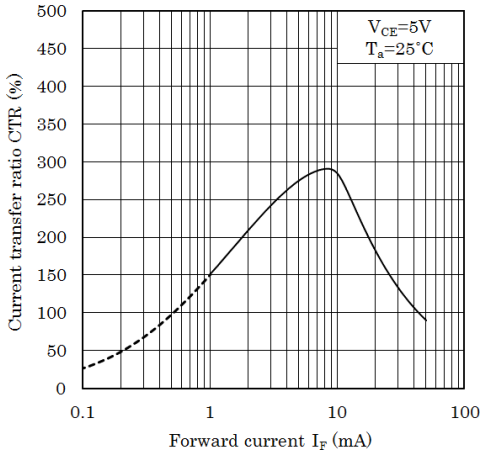


Fig.8 Collector Current vs. Collector-emitter Voltage

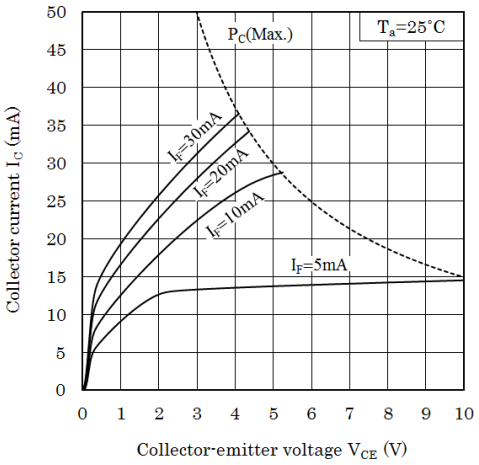


Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature

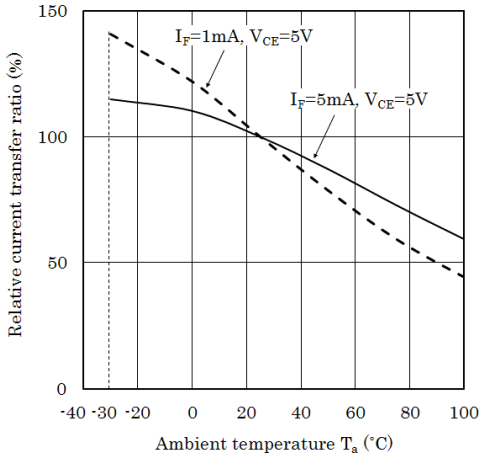


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

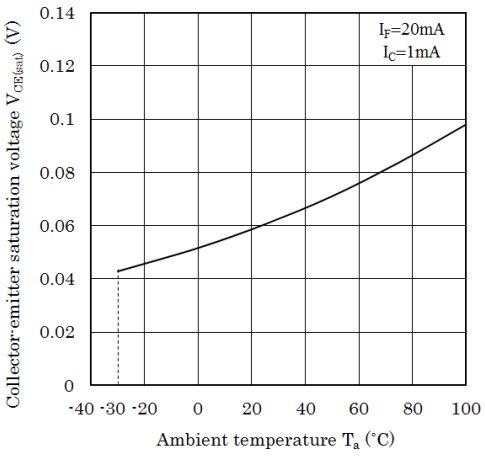
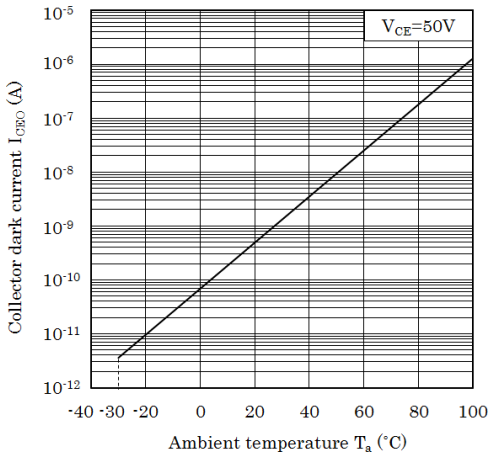


Fig.11 Collector Dark Current vs. Ambient Temperature

Fig.12 Collector-emitter Saturation Voltage vs. Forward Current


V_{CE}=50V
Collector dark current I_{CEO} (A)
10^{-5}
10^{-6}
10^{-7}
10^{-8}
10^{-9}
10^{-10}
10^{-11}
10^{-12}
-40 -30 -20 0 20 40 60 80 100
Ambient temperature T_a (°C)

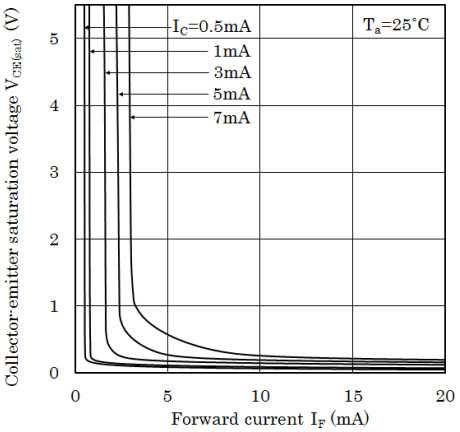

I_C=0.5mA
1mA
3mA
5mA
7mA
T_a=25°C
Collector-emitter saturation voltage $V_{CE(sat)}$ (V)
0 1 2 3 4 5
0 5 10 15 20
Forward current I_F (mA)

Fig.13 Response Time vs. Load Resistance

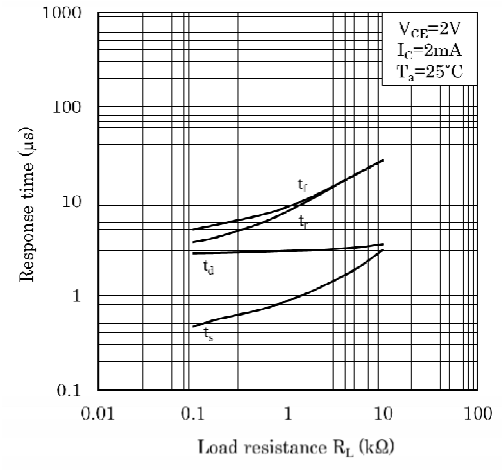


Fig.14 Test Circuit for Response Time

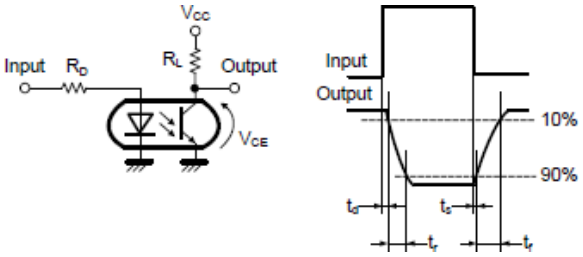


Fig.15 Frequency Response

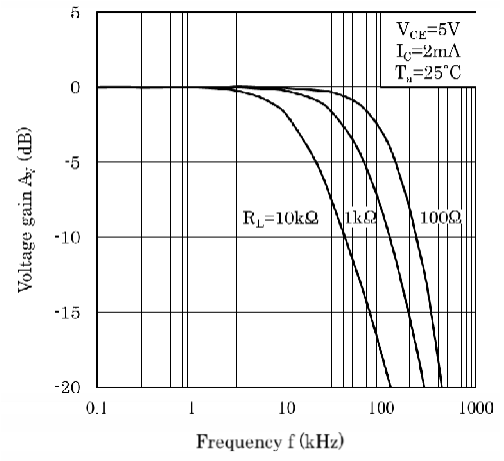
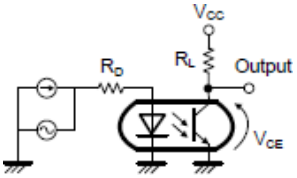


Fig.16 Test Circuit for Frequency Response



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.

■ Design Considerations

● Design guide

While operating at I_F<1mA, CTR variation may increase.
Please make design considering this fact.

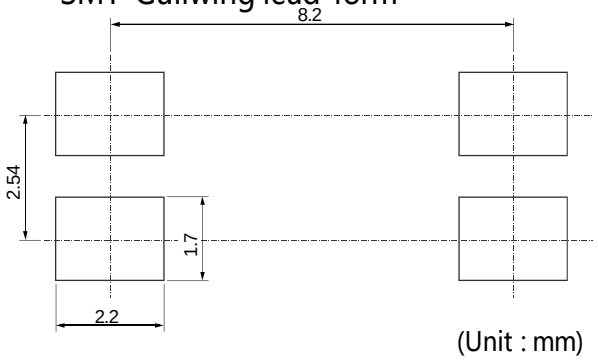
This product is not designed against irradiation and incorporates non-coherent IRED.

● Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.
In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

● Recommended foot print (reference)

SMT Gullwing lead-form



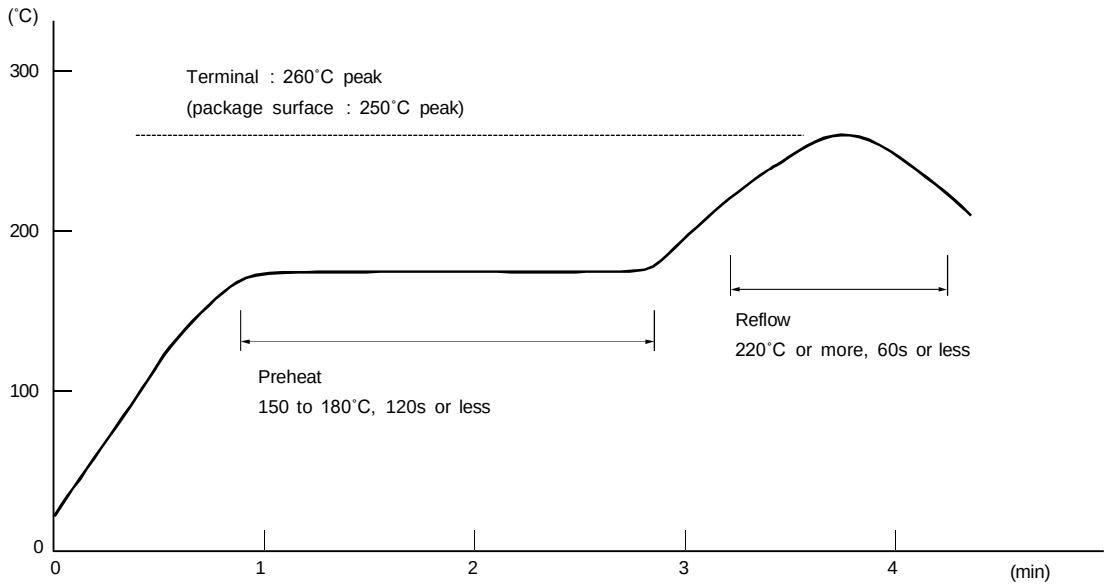
(Unit : mm)

■ Manufacturing Guidelines

● Soldering Method

Reflow Soldering :

Reflow soldering should follow the temperature profile shown below.
Soldering should not exceed the curve of temperature profile and time.
Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270℃ and within 10s.
Preheating is within the bounds of 100 to 150℃ and 30 to 80s.
Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400℃.
Please don't solder more than twice.

Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.

• Cleaning instructions

Solvent cleaning :

Solvent temperature should be 45˚C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning :

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.
Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials :

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.
In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packagingresin.

• Presence of ODC

This product shall not contain the following materials.
And they are not used in the production process for this product.
Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

(1) The RoHS directive(2011/65/EU)
This product complies with the RoHS directive(2011/65/EU)
Object substances: mercury, lead, cadmium, hexavalent chromium, polybrominated biphenyls (PBB) and polybrominated diphenyl ethers (PBDE)

(2) Content of six substances specified in Management Methods for Control of Pollution Caused by Electronic Information Products Regulation (Chinese : 电子信息产品污染控制管理办法).

Marking Styles for the Names and Contents of the Hazardous Substances

Category	Hazardous Substances					
	Lead (Pb)	Mercury (Hg)	Cadmium (Cd)	Hexavalent chromium (Cr^{6+})	Polybrominated biphenyls (PBB)	Polybrominated diphenyl ethers (PBDE)
Photocoupler	○	○	○	○	○	○

This table is prepared in accordance with the provisions of SJ/T 11364.
○ : Indicates that said hazardous substance contained in all of the homogeneous materials for this part is below the limit requirement of GB/T 26572.

■ Package specification

• Sleeve package

Through-Hole

Package materials

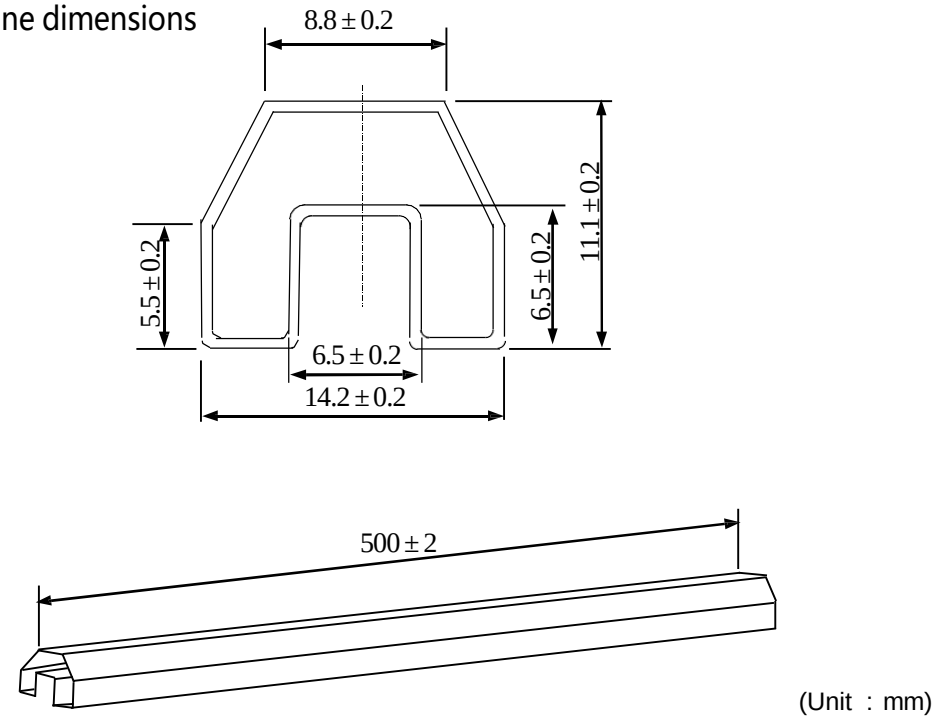
Sleeve : HIPS/PS or PC (with anti-staticmaterial)

Stopper : EPM

Package method

MAX. 100pcs. of products shall be packaged in a sleeve and both of sleeve edges shall be fixed by stoppers.
MAX. 25 sleeves (Product : 2,500pcs.) above shall be packaged in inner case and sealed by tape .
Max 2 bags(product : 5,000pcs) above shall be packaged in packing case , and put a cushioning material inside.

Sleeve outline dimensions



(Unit : mm)

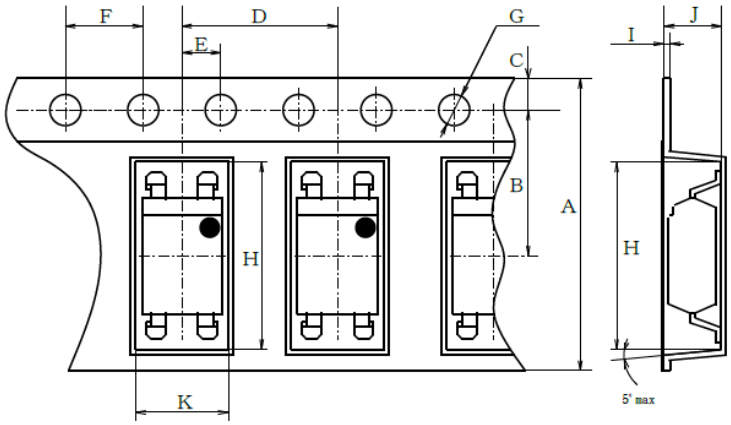
- **Tape and Reel package**

SMT Gullwing

Package materials

Carrier tape : PS
Cover tape : PET (three layer system)
Reel : PS

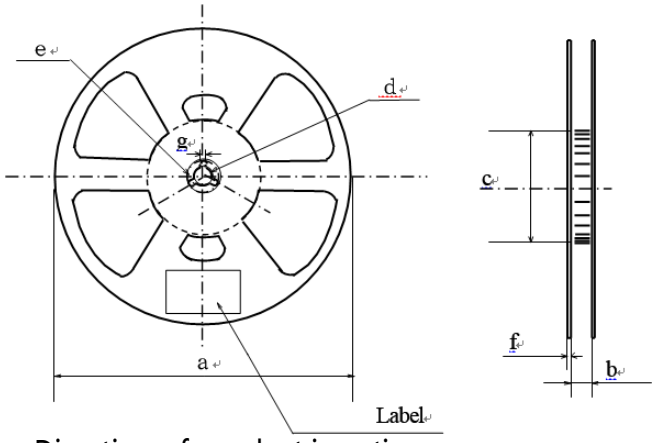
Carrier tape s[illegible]



Dimensions List (Unit : mm)

A	B	C	D	E	F	G
$16.0^{\pm0.3}$	$7.5^{\pm0.1}$	$1.75^{\pm0.10}$	$8.0^{\pm0.1}$	$2.0^{\pm0.1}$	$4.0^{\pm0.1}$	$\phi1.5^{+0.1}_{-0.0}$
H	I	J	K			
$10.3^{\pm0.1}$	$0.40^{\pm0.05}$	$4.0^{\pm0.1}$	$5.3^{\pm0.1}$			

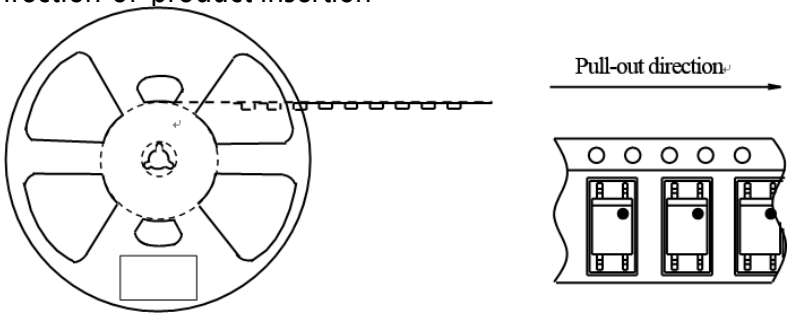
Reel structure and Dimensions



Dimensions List (Unit : mm)

a	b	c	d
$\phi330$	$17.5^{\pm1.5}$	$\phi100^{\pm1}$	$\phi13.0^{\pm0.5}$
e	f	g	
$\phi21.0^{\pm1}$	$2.0^{\pm0.5}$	$2.0^{\pm0.5}$	

Direction of product insertion



[Packing : 2,000pcs/reel]

■ Important Notices

·The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.

·Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents described herein at any time without notice in order to improve design or reliability. Manufacturing locations are also subject to change without notice.

·Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:

(i) The devices in this publication are designed for use in general electronic equipment designs such as:

--- Personal computers
--- Office automationequipment
--- Telecommunication equipment [terminal]
--- Test and measurement equipment
--- Industrial control
--- Audio visualequipment
--- Consumerelectronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

--- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
--- Trafficsignals
--- Gas leakage sensor breakers
--- Alarm equipment
--- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

--- Space applications
--- Telecommunication equipment [trunk lines]
--- Nuclear power control equipment
--- Medical and other life support equipment (e.g., scuba).

·If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.

·Contact and consult with a SHARP representative if there are any questions about the contents of this publication.